## Claims

- [c1] 1.A chip structure, at least comprising:
  a chip, having at least a bonding pad and a transmission
  line on a chip surface, wherein the transmission line is
  coupled to the bonding pad; and
  a passivation layer, covering the chip surface, wherein
  the passivation has an opening to expose the bonding
  pad, wherein a cross-section of the opening includes a
  straight line and an arc connecting to two ends of the
  straight line, and the straight line is near to a connection
  terminal between the transmission line and the bonding
  pad.
- [c2] 2. The chip structure of claim 1, wherein a length of the straight line is less than or equal to a radius of the arc.
- [c3] 3. The chip structure of claim 1, wherein a length of the straight line is between a radius of the arc and a diameter of the arc.
- [04] 4. The chip structure of claim 1, wherein the passivation layer includes an organic passivation layer.
- [05] 5. The chip structure of claim 1, wherein the passivation layer includes an inorganic passivation layer.

- [c6] 6. A chip structure, at least comprising:
  a chip, having at least a bonding pad and a transmission
  line coupled to the bonding pad, wherein the bonding
  pad and the transmission line are on a chip surface; and
  a passivation layer, covering the chip surface, wherein
  the passivation has an opening to expose the bonding
  pad, wherein a cross section of the opening includes a
  curving line and an arc connecting to two ends of the
  curving line, wherein the curving line is concave to the
  arc and near to a connection terminal between the transmission line and the bonding pad.
- [c7] 7. The chip structure of claim 6, wherein each point of the curving line has a substantially equal distance to the connection terminal between the transmission line and the bonding pad.
- [08] 8. The chip structure of claim 6, wherein a curvature of the curving line is less than or equal to a curvature of the arc.
- [09] 9. The chip structure of claim 6, wherein a curvature of the curving line is greater than or equal to a curvature of the arc.
- [c10] 10. The chip structure of claim 6, wherein the passivation layer includes an organic passivation layer.

[c11] 11. The chip structure of claim 6, wherein the passivation layer includes an inorganic passivation layer.